



### 20V N-Channel Enhancement Mode MOSFET - ESD Protected

Voltage 20 V Current 1.2 A

#### **Features**

- RDS(ON) , VGS@4.5V, ID@1.2A<380mΩ</li>
- RDS(ON) , VGS@2.5V, ID@0.7A<680mΩ</li>
- RDS(ON) , VGS@1.8V, ID@0.2A<1100mΩ(typ.)</li>
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

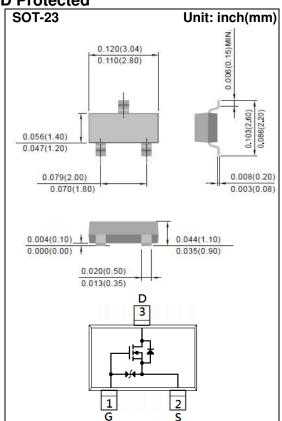
#### **Mechanical Data**

• Case: SOT-23 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.0003 ounces, 0.0084 grams

Marking: A36



### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	20	V
Gate-Source Voltage		$V_{GS}$	<u>+</u> 12	V
Continuous Drain Current		I <sub>D</sub>	1.2	Α
Pulsed Drain Current (Note 4)		I <sub>DM</sub>	4.8	Α
Power Dissipation	T <sub>a</sub> =25°C	P <sub>D</sub>	1.25	W
	Derate above 25°C		10	mW/°C
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	°C
Typical Thermal resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	100	°C/W





# **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250uA$	0.4	0.65	1.0	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	$V_{GS}$ =4.5V, $I_{D}$ =1.2A	-	310	380	mΩ
		$V_{GS}$ =2.5V, $I_{D}$ =0.7A	-	440	680	
		$V_{GS}$ =1.8V, $I_{D}$ =0.2A	-	700	-	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =16V, $V_{GS}$ =0V	-	0.02	1	uA
Gate-Source Leakage Current	$I_{GSS}$	V <sub>GS</sub> = <u>+</u> 10V, V <sub>DS</sub> =0V	-	<u>+</u> 2	<u>+</u> 10	uA
Dynamic						
Total Gate Charge	$Q_g$	V <sub>DS</sub> =10V, I <sub>D</sub> =1.2A, V <sub>GS</sub> =4.5V <sup>(Note 1,2)</sup>	-	0.9	-	nC
Gate-Source Charge	$Q_{gs}$		-	0.2	-	
Gate-Drain Charge	$Q_gd$		-	0.2	-	
Input Capacitance	Ciss	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V,	-	39	-	pF
Output Capacitance	Coss		-	15	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	9	-	
Switching						
Turn-On Delay Time	td <sub>(on)</sub>	$\begin{array}{c} V_{DD}{=}10V,\ I_{D}{=}1.2A,\\ V_{GS}{=}4.5V,\\ R_{G}{=}6\Omega \end{array}$	-	2.2	-	ns
Turn-On Rise Time	tr		-	22	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	9	-	
Turn-Off Fall Time	tf		-	20	-	
Drain-Source Diode						
Maximum Continuous Drain-Source					1.0	Α
Diode Forward Current	I <sub>S</sub>		-	-	1.0	
Diode Forward Voltage	$V_{\text{SD}}$	I <sub>S</sub> =1.0A, V <sub>GS</sub> =0V	-	0.93	1.3	V

### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.





#### **TYPICAL CHARACTERISTIC CURVES**

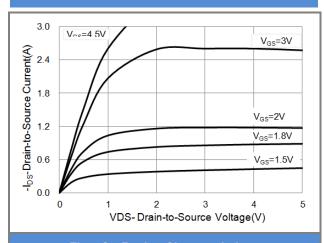


Fig.1 On-Region Characteristics

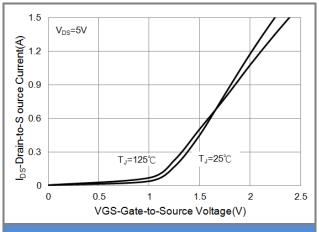


Fig.2 Transfer Characteristics

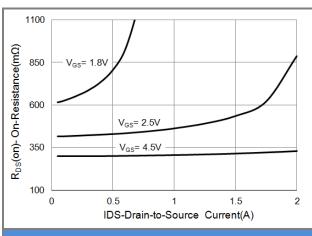


Fig.3 On-Resistance vs. Drain Current

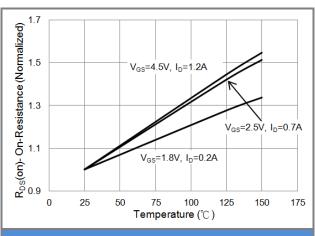


Fig.4 On-Resistance vs. Junction temperature

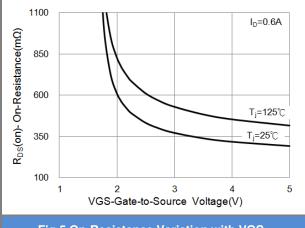
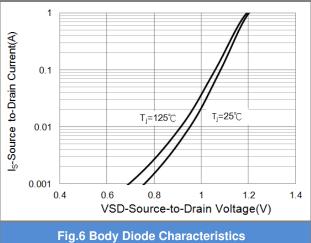


Fig.5 On-Resistance Variation with VGS.







### **TYPICAL CHARACTERISTIC CURVES**

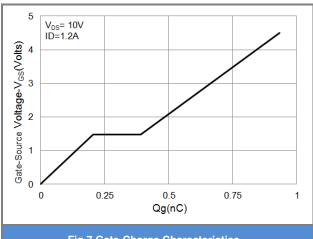


Fig.7 Gate-Charge Characteristics

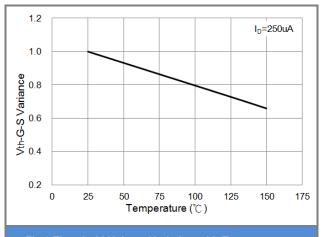


Fig.8 Threshold Voltage Variation with Temperature.

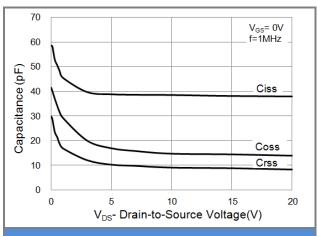


Fig.9 Threshold Voltage Variation with Temperature.

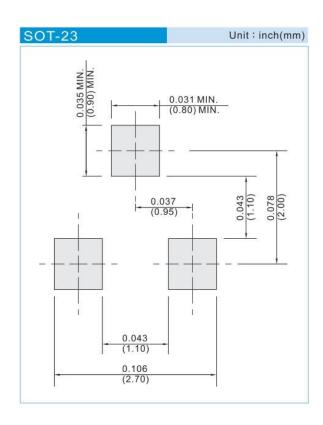




### PART NO PACKING CODE VERSION

PART NO PACKING CODE	Package Type	Packing type	Marking	Version
PJA3436_R1_00001	SOT-23	3K pcs / 7" reel	A36	Halogen free
PJA3436_R2_00001	SOT-23	12K pcs / 13" reel	A36	Halogen free

### **MOUNTING PAD LAYOUT**







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